Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSVII)

TK8A65D

Switching Regulator Applications

• Low drain-source ON-resistance: RDS (ON) = 0.7Ω (typ.)

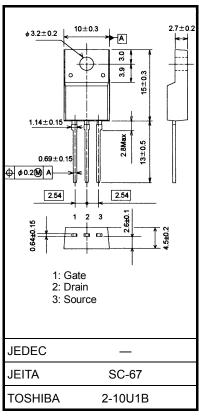
• High forward transfer admittance: $|Y_{fs}| = 4.5 \text{ S (typ.)}$

• Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 650 \text{ V)}$

• Enhancement mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	650	V
Gate-source voltage		V_{GSS}	±30	V
Drain current	DC (Note 1)	I _D	8	Α
	Pulse (Note 1)	I _{DP}	32	^
Drain power dissipation	on (Tc = 25°C)	P _D	45	W
Single pulse avalanche energy (Note 2)		E _{AS}	416	mJ
Avalanche current		I _{AR}	8	Α
Repetitive avalanche energy (Note 3)		E _{AR}	4.5	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

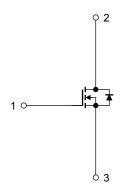
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 11.5 mH, $R_G = 25 \Omega$, $I_{AR} = 8 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



Start of commercial production 2009-01

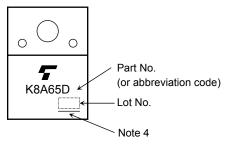
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Drain cut-off current		I _{DSS}	V _{DS} = 650 V, V _{GS} = 0 V	_	_	10	μА
Drain-source brea	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	650	_	_	V
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V
Drain-source ON	-resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 4 A	_	0.7	0.84	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 4 A	1.3	4.5	_	S
Input capacitance		C _{iss}		_	1350	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	6	_	
Output capacitance		Coss		_	135	_	
Switching time	Rise time	t _r	$\begin{array}{c c} 10 \text{ V} & I_D = 4 \text{ A} & V_{OUT} \\ \hline 0 \text{ V} & R_L = 50 \Omega \end{array}$	_	22	_	ns
	Turn-on time	t _{on}		_	55	_	
	Fall time	t _f		_	15	_	
	Turn-off time	t _{off}	$V_{DD} \approx 200 \text{ V}$ Duty \leq 1%, $t_W = 10 \mu\text{s}$	_	100	_	
Total gate charge		Qg		_	25	_	
Gate-source charge		Q _{gs}	V _{DD} ≈ 400 V, V _{GS} = 10 V, I _D = 8 A	_	16	_	nC
Gate-drain charge		Q _{gd}		_	9	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

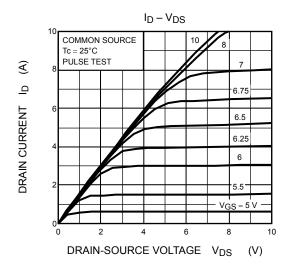
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	8	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	32	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 8 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 8 A, V _{GS} = 0 V,	_	1300	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	12	_	μС

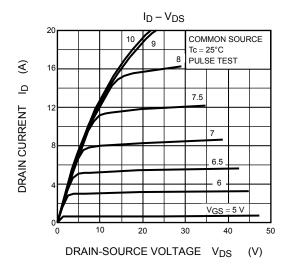
Marking

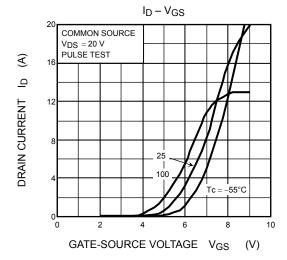


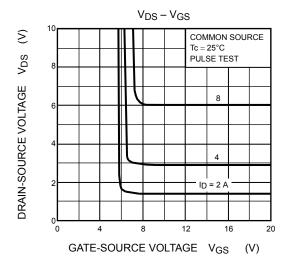
Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

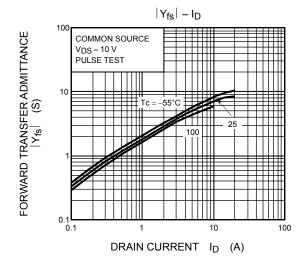
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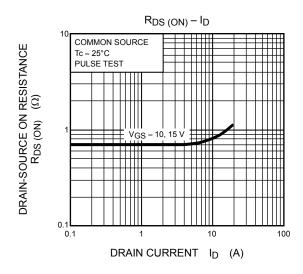


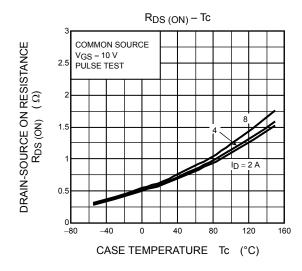


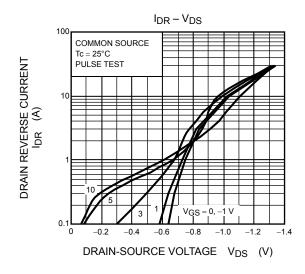


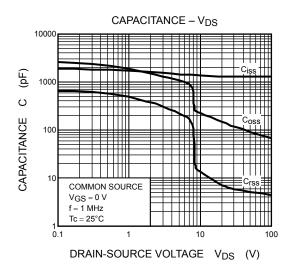


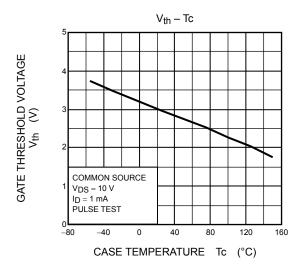


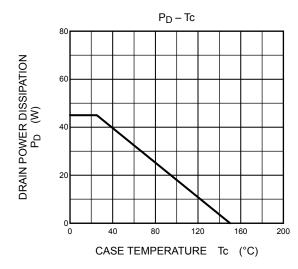


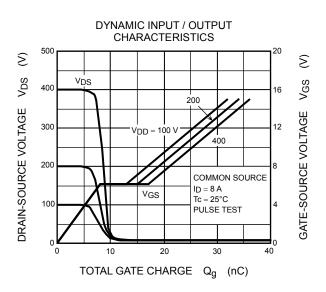


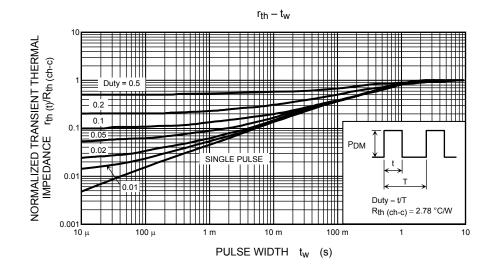


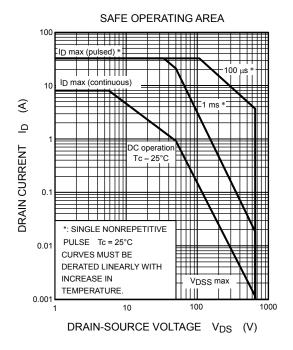


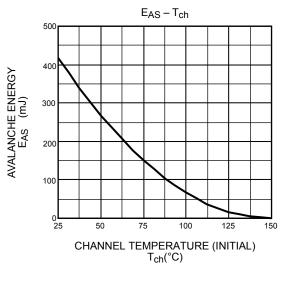


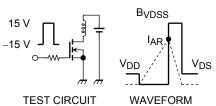












$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 90~V,~L = 11.5~mH \end{aligned} \qquad EAS &= \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right) \end{aligned}$$

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